





#### 40V PNP HIGH GAIN LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

#### **Features**

- BV<sub>CEO</sub> > -40V
- I<sub>C</sub> = -5.5A High Continuous Current
- I<sub>CM</sub> = -15A Peak Pulse Current
- $R_{CE(SAT)} = 29m\Omega$  for a low equivalent On-Resistance
- Low Saturation Voltage V<sub>CE(SAT)</sub> < -60mV @ -1A</li>
- hFE Specified Up to -10A for High Current Gain Hold Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- · Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

#### **Mechanical Data**

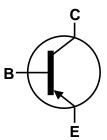
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight: 0.05 grams (Approximate)

## **Applications**

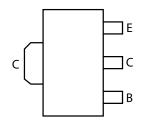
- Charging Circuits
- DC-DC Converters
- MOSFET and IGBT Gate Driving
- Power Switches
- Motor Control







Device Symbol



Top View Pin Out

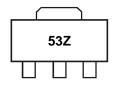
#### **Ordering Information (Note 5)**

| Product   | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|-----------|------------|---------|--------------------|-----------------|-------------------|
| ZX5T3ZTA  | AEC-Q101   | 53Z     | 7                  | 12              | 1,000             |
| ZX5T3ZQTA | Automotive | 53Z     | 7                  | 12              | 1,000             |
| ZX5T3ZTC  | AEC-Q101   | 53Z     | 13                 | 12              | 4,000             |
| ZX5T3ZQTC | Automotive | 53Z     | 13                 | 12              | 4,000             |

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- $5.\ For\ packaging\ details,\ go\ to\ our\ website\ at\ http"//www.diodes.com/products/packages.html.$

## **Marking Information**



53Z = Product Type Marking Code





## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic               | Symbol           | Limit | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage       | V <sub>CBO</sub> | -50   | V    |
| Collector-Base Voltage       | V <sub>CBS</sub> | -50   | V    |
| Collector-Emitter Voltage    | V <sub>CEO</sub> | -40   | V    |
| Emitter-Base Voltage         | $V_{EBO}$        | -7.5  | V    |
| Continuous Collector Current | Ic               | -5.5  | Α    |
| Peak Pulse Current           | I <sub>CM</sub>  | -15   | Α    |

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic                                 | Symbol                            | Value             | Unit |      |  |
|--|-----------------------------------|-------------------|------|------|--|
|  | (Note 6)                          |                   | 0.9  |      |  |
| Dower Dissipation                              | (Note 7)                          |                   | 1.5  | W    |  |
| Power Dissipation                              | (Note 8)                          | P <sub>D</sub>    | 2.1  | VV   |  |
|  | (Note 9)                          |                   | 3.0  |      |  |
|  | (Note 6)                          |                   | 139  | 0000 |  |
| The second Designation of Austrian Air         | (Note 7)                          | ]                 | 83   | °C/W |  |
| Thermal Resistance, Junction to Ambient Air    | (Note 8)                          | $R_{\theta JA}$   | 60   |      |  |
|  | (Note 9)                          |                   | 42   |      |  |
| Thermal Resistance, Junction to Lead (Note 10) |                                   | R <sub>0</sub> JL | 2.81 | °C/W |  |
| Operating and Storage Temperature Range        | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150       | °C   |      |  |

## ESD Ratings (Note 11)

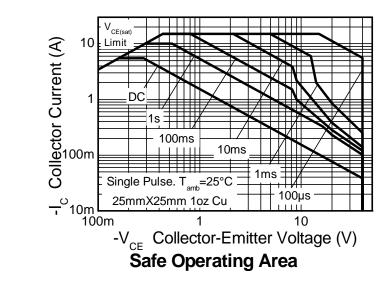
| Characteristic                             | Symbol  | Value   | Unit | JEDEC Class |
|--|---------|---------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | ≥ 4,000 | V    | 3A          |
| Electrostatic Discharge - Machine Model    | ESD MM  | ≥ 400   | V    | С           |

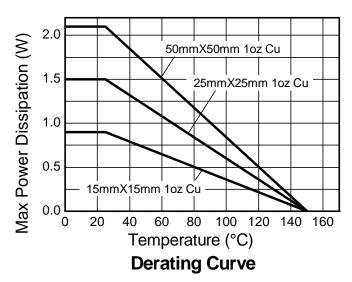
Notes:

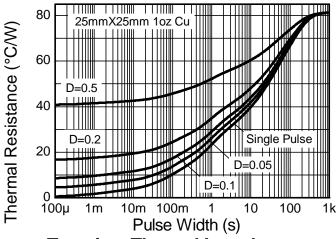
- 6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as note (6), except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Same as note (6), except the device is mounted on 50mm x 50mm 1oz copper.
- 9. Same as note (6), except the device is mounted on 25mm x 25mm 1oz copper and measured at t<5secs.
- 10. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

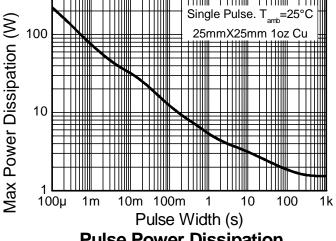


## **Thermal Characteristics and Derating Information**









**Transient Thermal Impedance** 

**Pulse Power Dissipation** 





## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

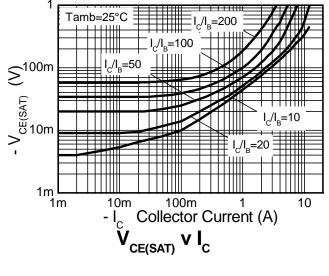
| Characteristic                                 | Symbol                | Min                      | Тур  | Max  | Unit | Test Condition  |  |
|--|-----------------------|--------------------------|--|--|------|---|--|
| Collector-Base Breakdown Voltage               | BV <sub>CBO</sub>     | -50                      | -90  | _  | V    | $I_C = -100 \mu A$  |  |
| Collector-Emitter Breakdown Voltage            | BV <sub>CES</sub>     | -50                      | -90  | _  | V    | $I_C = -100 \mu A$  |  |
| Collector-Emitter Breakdown Voltage (Note 12)  | BV <sub>CEO</sub>     | -40                      | -58  | _  | V    | $I_C = -10mA$   |  |
| Emitter-Base Breakdown Voltage                 | BV <sub>EBO</sub>     | -7.5                     | -8.3   | _  | V    | I <sub>E</sub> = -100μA   |  |
| Collector Cutoff Current                       | I <sub>CBO</sub>      | _                        | <1   | -20  | nA   | V <sub>CB</sub> = -40V  |  |
| Collector Cutoff Current                       | I <sub>CES</sub>      | _                        | <1   | -20  | nA   | V <sub>CE</sub> = -32V  |  |
| Emitter Cutoff Current                         | I <sub>EBO</sub>      | _                        | <1   | -20  | nA   | V <sub>EB</sub> = -6V   |  |
| DC Current Transfer Static Ratio (Note 12)     | h <sub>FE</sub>       | 200<br>200<br>170<br>110 | 390<br>350<br>290<br>175                                 | <br>550<br><br>                                  | _    | I <sub>C</sub> = -10mA, V <sub>CE</sub> = -2V<br>I <sub>C</sub> = -0.5A, V <sub>CE</sub> = -2V<br>I <sub>C</sub> = -2A, V <sub>CE</sub> = -2V<br>I <sub>C</sub> = -5.5A, V <sub>CE</sub> = -2V  |  |
| Collector-Emitter Saturation Voltage (Note 12) | V <sub>CE</sub> (SAT) | _<br>_<br>_              | -15<br>-44<br>-50<br>-120<br>-70<br>-125<br>-130<br>-162 | -30<br>-60<br>-70<br>-165<br>-80<br>-175<br>-175 | mV   | $\begin{split} &I_{C}=-0.1A,\ I_{B}=-10mA\\ &I_{C}=-1A,\ I_{B}=-100mA\\ &I_{C}=-1A,\ I_{B}=-50mA\\ &I_{C}=-1A,\ I_{B}=-10mA\\ &I_{C}=-2A,\ I_{B}=-200mA\\ &I_{C}=-2A,\ I_{B}=-40mA\\ &I_{C}=-3.5A,\ I_{B}=-175mA\\ &I_{C}=-5.5A,\ I_{B}=-550mA \end{split}$ |  |
| Base-Emitter Saturation Voltage (Note 12)      | V <sub>BE(SAT)</sub>  | _                        | -820<br>-1000  | -900<br>-1075                                    | V    | $I_C = -2A$ , $I_B = -40mA$<br>$I_C = -5.5A$ , $I_B = -550mA$   |  |
| Base-Emitter Turn-On Voltage (Note 12)         | V <sub>BE(ON)</sub>   | _                        | -778<br>-869   | -850<br>-950                                     | V    | I <sub>C</sub> = -2A, V <sub>CE</sub> = -2V<br>I <sub>C</sub> = -5.5A, V <sub>CE</sub> = -2V  |  |
| Transitional Frequency                         | f <sub>T</sub>        | _                        | 152  | _  | MHz  | I <sub>C</sub> = -50mA, V <sub>CE</sub> = -10V<br>f = 100MHz  |  |
| Output Capacitance                             | C <sub>obo</sub>      | _                        | 53   | _  | pF   | V <sub>CB</sub> = -10V, f = 1MHz,   |  |
|  | t <sub>d</sub>        |                          | 18   |  | nS   | I <sub>C</sub> = -1A, V <sub>CC</sub> = -10V  |  |
| Switching Times                                | t <sub>r</sub>        | _                        | 17   | _  |      |   |  |
| Switching Times                                | ts                    |                          | 325  |  |      | $I_{B1} = -I_{B2} = -100 \text{mA}$   |  |
|  | t <sub>f</sub>        |                          | 60   |  |      |   |  |
|  | t <sub>d</sub>        |                          | 55   |  | nS   |   |  |
| Switching Times                                | t <sub>r</sub>        |                          | 107  |  |      | $I_C = -2A$ , $V_{CC} = -30V$<br>$I_{B1} = -I_{B2} = -20mA$   |  |
| Switching Times                                | ts                    |                          | 264  |  |      |   |  |
|  | t <sub>f</sub>        |                          | 103  |  |      |   |  |

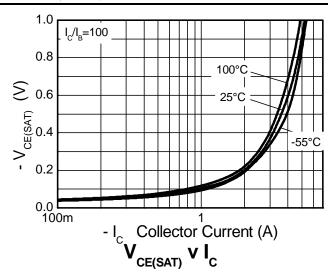
Note:

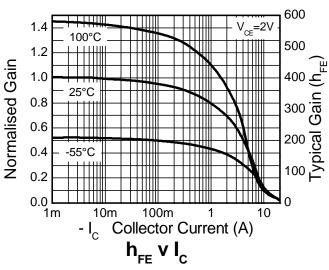
12. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

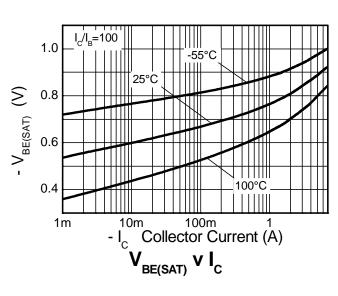


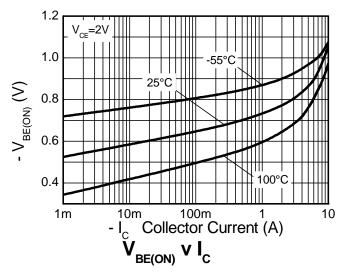
 $\textbf{Typical Electrical Characteristics} \ (@T_{A} = +25^{\circ}C, \text{ unless otherwise specified.})$ 







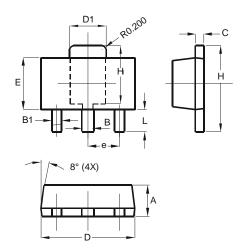






# **Package Outline Dimensions**

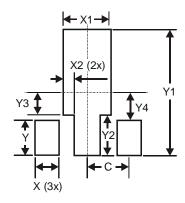
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT89                |          |      |  |  |
|----------------------|----------|------|--|--|
| Dim                  | Min      | Max  |  |  |
| Α                    | 1.40     | 1.60 |  |  |
| В                    | 0.44     | 0.62 |  |  |
| B1                   | 0.35     | 0.54 |  |  |
| C                    | 0.35     | 0.44 |  |  |
| D                    | 4.40     | 4.60 |  |  |
| D1                   | 1.62     | 1.83 |  |  |
| Е                    | 2.29     | 2.60 |  |  |
| е                    | 1.50 Typ |      |  |  |
| Н                    | 3.94     | 4.25 |  |  |
| H1                   | 2.63     | 2.93 |  |  |
| L                    | 0.89     | 1.20 |  |  |
| All Dimensions in mm |          |      |  |  |

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Х          | 0.900         |
| X1         | 1.733         |
| X2         | 0.416         |
| Υ          | 1.300         |
| Y1         | 4.600         |
| Y2         | 1.475         |
| Y3         | 0.950         |
| Y4         | 1.125         |
| С          | 1.500         |





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